



A Product Line of Diodes Incorporated

FMMT493

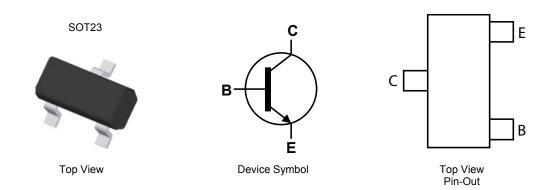
#### **100V NPN MEDIUM POWER TRANSISTOR IN SOT23**

#### Features

- BV<sub>CEO</sub> > 100V
- I<sub>C</sub> = 1A High Continuous Collector Current
- I<sub>CM</sub> = 2A Peak Pulse Current
- 500mW Power Dissipation
- hFE Characterised Up to 2A for High Current Gain Hold Up
- Complementary PNP Type: FMMT593
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP capable (Note 4)

#### **Mechanical Data**

- Case: SOT23
- Case material: Molded Plastic. "Green" Molding Compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 <sup>(3)</sup>
- Weight: 0.008 grams (Approximate)



### Ordering Information (Notes 4 & 5)

| Part Number | Compliance | Marking | Reel size (inches) | Tape width (mm) | Quantity per reel |
|-------------|------------|---------|--------------------|-----------------|-------------------|
| FMMT493TA   | AEC-Q101   | 493     | 7                  | 8               | 3,000             |
| FMMT493QTA  | Automotive | 493     | 7                  | 8               | 3,000             |
| FMMT493TC   | AEC-Q101   | 493     | 13                 | 8               | 10,000            |

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

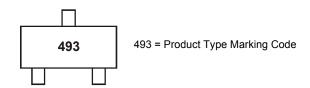
2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product\_compliance\_definitions/.

5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**







# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic               | Symbol           | Value | Unit |
|------------------------------|------------------|-------|------|
| Collector-Base Voltage       | V <sub>CBO</sub> | 120   | V    |
| Collector-Emitter Voltage    | V <sub>CEO</sub> | 100   | V    |
| Emitter-Base Voltage         | V <sub>EBO</sub> | 7     | V    |
| Continuous Collector Current | Ic               | 1     | A    |
| Peak Pulse Current           | I <sub>CM</sub>  | 2     | A    |
| Base Current                 | IB               | 200   | mA   |

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic                                   | Symbol                           | Value       | Unit |
|--|----------------------------------|-------------|------|
| Power Dissipation (Note 6)                       | PD                               | 500         | mW   |
| Thermal Resistance, Junction to Ambient (Note 6) | R <sub>0JA</sub>                 | 250         | °C/W |
| Thermal Resistance, Junction to Lead (Note 7)    | R <sub>θJL</sub>                 | 197         | °C/W |
| Operating and Storage Temperature Range          | T <sub>J,</sub> T <sub>STG</sub> | -55 to +150 | °C   |

## ESD Ratings (Note 8)

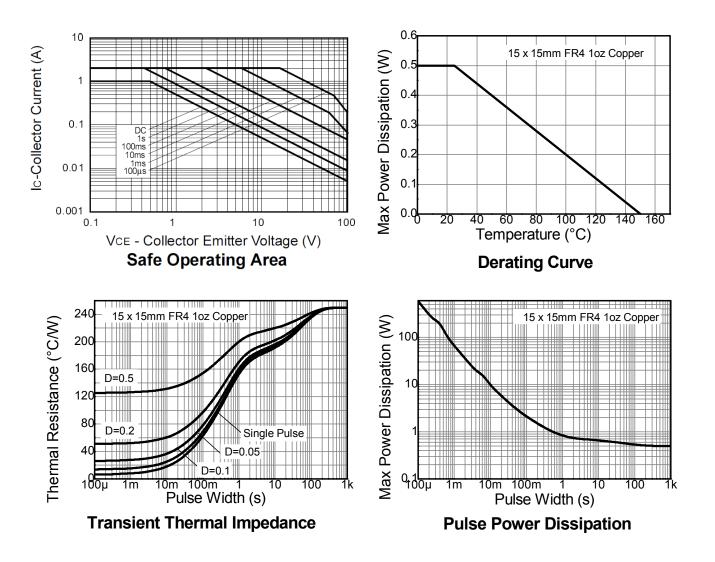
| Characteristic                             | Symbol  | Value | Unit | JEDEC Class |
|--|---------|-------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | 4,000 | V    | 3A          |
| Electrostatic Discharge - Machine Model    | ESD MM  | ≥ 400 | V    | С           |

Notes: 6. For a device mounted on 15mm X 15mm 1oz weight copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state. 7. Thermal resistance from junction to solder-point (at the end of the collector lead). 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.





# **Thermal Characteristics and Derating Information**







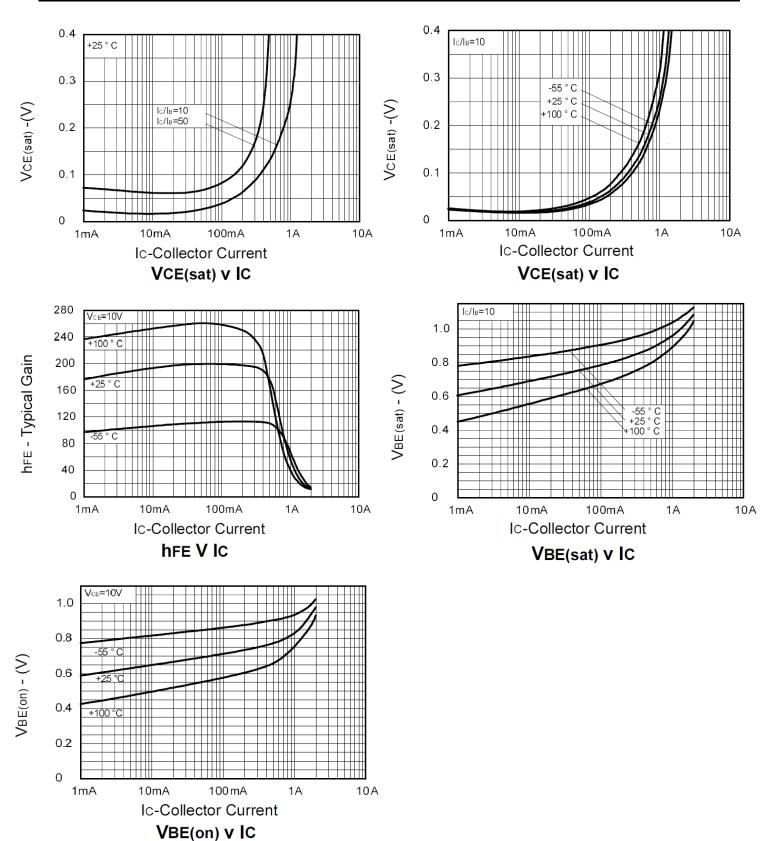
| Characteristic                                 | Symbol               | Min                    | Тур  | Мах         | Unit     | Test Condition  |
|--|----------------------|------------------------|------|-------------|----------|---|
| Collector-Base Breakdown Voltage               | BV <sub>CBO</sub>    | 120                    | _    | _           | V        | I <sub>C</sub> = 100μA  |
| Collector-Emitter Breakdown Voltage (Note 9)   | BV <sub>CEO</sub>    | 100                    | —    | —           | V        | I <sub>C</sub> = 1mA  |
| Emitter-Base Breakdown Voltage                 | BV <sub>EBO</sub>    | 7                      | —    | —           | V        | I <sub>E</sub> = 100μA  |
| Collector Cutoff Current                       | I <sub>CBO</sub>     | _                      | —    | 100         | nA       | V <sub>CB</sub> = 100V  |
| Emitter Cutoff Current                         | I <sub>EBO</sub>     | _                      | _    | 50          | nA       | V <sub>EB</sub> = 5.6V  |
| Collector Emitter Cutoff Current               | ICES                 | _                      | _    | 100         | nA       | V <sub>CE</sub> = 100V  |
| Static Forward Current Transfer Ratio (Note 9) | h <sub>FE</sub>      | 100<br>100<br>60<br>20 | <br> | <br>300<br> | _        | $\begin{split} I_{C} &= 1mA,  V_{CE} = 10V \\ I_{C} &= 250mA,  V_{CE} = 10V \\ I_{C} &= 500mA,  V_{CE} = 10V \\ I_{C} &= 1A,  V_{CE} = 10V \end{split}$ |
| Collector-Emitter Saturation Voltage (Note 9)  | V <sub>CE(sat)</sub> | _                      | _    | 300<br>600  | mV<br>mV | I <sub>C</sub> = 500mA, I <sub>B</sub> = 50mA<br>I <sub>C</sub> = 1A, I <sub>B</sub> = 100mA  |
| Base-Emitter Turn-On Voltage(Note 9)           | V <sub>BE(on)</sub>  |                        | —    | 1.0         | V        | $I_{C}$ = 1A, $V_{CE}$ = 10V  |
| Base-Emitter Saturation Voltage(Note 9)        | V <sub>BE(sat)</sub> | _                      | _    | 1.15        | V        | I <sub>C</sub> = 1A, I <sub>B</sub> = 100mA   |
| Output Capacitance                             | C <sub>obo</sub>     | _                      | _    | 10          | pF       | V <sub>CB</sub> = 10V, f = 1MHz   |
| Transition Frequency                           | f⊤                   | 150                    | _    | _           | MHz      | $V_{CE}$ = 10V, I <sub>C</sub> = 50mA,<br>f = 100MHz  |

Note: 9. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%.







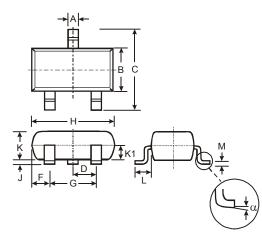






## **Package Outline Dimensions**

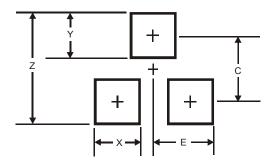
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



| SOT23                |       |      |       |  |  |
|----------------------|-------|------|-------|--|--|
| Dim                  | Min   | Max  | Тур   |  |  |
| Α                    | 0.37  | 0.51 | 0.40  |  |  |
| В                    | 1.20  | 1.40 | 1.30  |  |  |
| С                    | 2.30  | 2.50 | 2.40  |  |  |
| D                    | 0.89  | 1.03 | 0.915 |  |  |
| F                    | 0.45  | 0.60 | 0.535 |  |  |
| G                    | 1.78  | 2.05 | 1.83  |  |  |
| Н                    | 2.80  | 3.00 | 2.90  |  |  |
| J                    | 0.013 | 0.10 | 0.05  |  |  |
| κ                    | 0.903 | 1.10 | 1.00  |  |  |
| K1                   | -     | -    | 0.400 |  |  |
| L                    | 0.45  | 0.61 | 0.55  |  |  |
| М                    | 0.085 | 0.18 | 0.11  |  |  |
| α                    | 0°    | 8°   | -     |  |  |
| All Dimensions in mm |       |      |       |  |  |

## **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| Z          | 2.9           |
| Х          | 0.8           |
| Y          | 0.9           |
| С          | 2.0           |
| E          | 1.35          |



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